

0.5A High-Speed MOSFET Drivers

Features

- Latch-Up Protected: Will Withstand 500 mA Reverse Current
- Input Will Withstand Negative Inputs up to 5V
- Electrostatic Discharge (ESD) Protected: 2.0 kV (HBM) and 400V (MM)
- High Peak Output Current: 0.5A
- Wide Input Supply Voltage Operating Range:
 - 4.5V to 16V
- High Capacitive Load Drive Capability:
 - 500 pF in 25 ns
- Short Delay Time: 30 ns typical
- Consistent Delay Times With Changes in Supply Voltage
- Matched Delay Times
- Low Supply Current
 - With Logic '1' Input: 500 μ A
 - With Logic '0' Input: 100 μ A
- Low Output Impedance: 16 Ω
- Available in Space-Saving 8-pin MSOP Package
- Pinout – same as TC1411/TC1412/TC1413

Applications

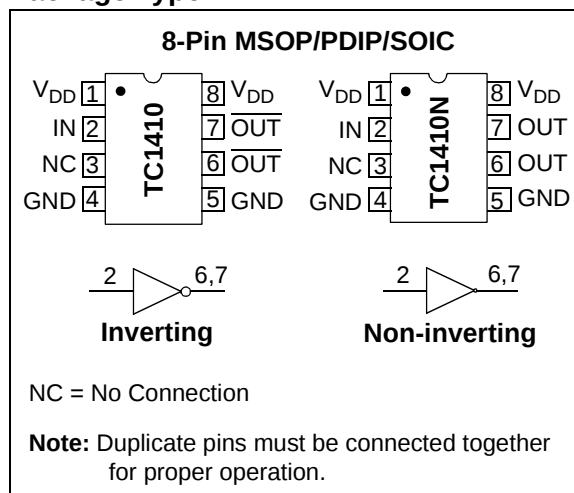
- Switch Mode Power Supplies
- Line Drivers
- Pulse Transformer Drive
- Relay Driver

General Description

The TC1410/TC1410N are 0.5A CMOS buffers/drivers. They will not latch up under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of current of either polarity being forced back into their output. All terminals are fully protected against Electrostatic Discharge (ESD) up to 2.0 kV (HBM) and 400V (MM).

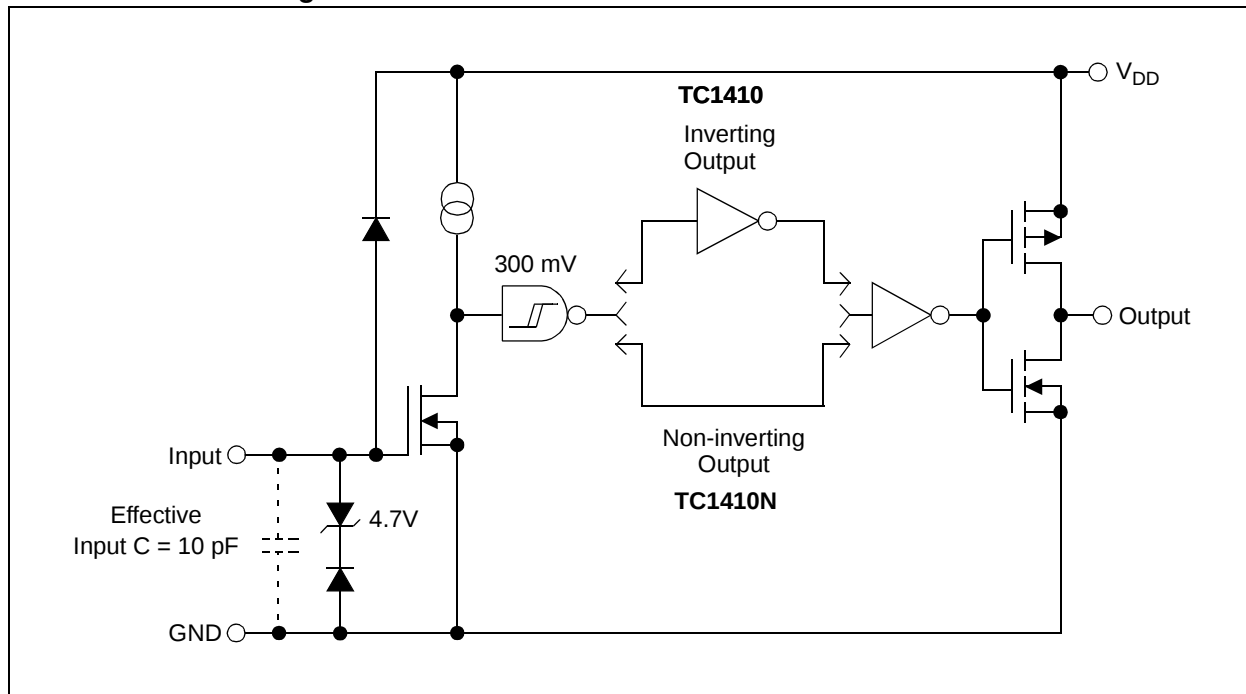
As MOSFET drivers, the TC1410/TC1410N can easily charge a 500 pF gate capacitance in 25 ns with matched rise and fall times and provide low enough impedance in both the 'ON' and 'OFF' states to ensure the MOSFET's intended state will not be affected, even by large transients. The leading and trailing edge propagation delay times are also matched to allow driving short-duration inputs with greater accuracy.

Package Type



TC1410/TC1410N

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Supply Voltage	+20V
Input Voltage	$V_{DD} + 0.3V$ to GND – 5.0V
Power Dissipation ($T_A \leq 70^\circ C$)	
MSOP	340 mW
PDIP	730 mW
SOIC	470 mW
Storage Temperature Range	-65°C to +150°C
Maximum Junction Temperature	+150°C

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, over the operating temperature range with $4.5V \leq V_{DD} \leq 16V$. Typical values are measured at $T_A = +25^\circ C$, $V_{DD} = 16V$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Input						
Logic '1', High Input Voltage	V _{IH}	2.0	—	—	V	
Logic '0', Low Input Voltage	V _{IL}	—	—	0.8	V	
Input Current	I _{IN}	-1	—	1	μA	0V ≤ V _{IN} ≤ V _{DD} , T _A = +25°C
		-10	—	10		-40°C ≤ T _A ≤ +85°C
Output						
High Output Voltage	V _{OH}	V _{DD} − 0.025	—	—	V	DC Test
Low Output Voltage	V _{OL}	—	—	0.025	V	DC Test
Output Resistance	R _O	—	16	22	Ω	V _{DD} = 16V, I _O = 10 mA, T _A = +25°C
		—	20	28		0°C ≤ T _A ≤ +70°C
		—	20	28		-40°C ≤ T _A ≤ +85°C
Peak Output Current	I _{PK}	—	0.5	—	A	V _{DD} = 16V
Latch-Up Protection Withstand Reverse Current	I _{REV}	—	0.5	—	A	Duty cycle ≤ 2%, t ≤ 300 μs, V _{DD} = 16V
Switching Time (Note 1)						
Rise Time	t _R	—	25	35	ns	T _A = +25°C
		—	27	40		0°C ≤ T _A ≤ +70°C
		—	29	40		-40°C ≤ T _A ≤ +85°C, Figure 4-1
Fall Time	t _F	—	25	35	ns	T _A = +25°C
		—	27	40		0°C ≤ T _A ≤ +70°C
		—	29	40		-40°C ≤ T _A ≤ +85°C, Figure 4-1
Delay Time	t _{D1}	—	30	40	ns	T _A = +25°C
		—	33	45		0°C ≤ T _A ≤ +70°C
		—	35	45		-40°C ≤ T _A ≤ +85°C, Figure 4-1
Delay Time	t _{D2}	—	30	40	ns	T _A = +25°C
		—	33	45		0°C ≤ T _A ≤ +70°C
		—	35	45		-40°C ≤ T _A ≤ +85°C, Figure 4-1

Note 1: Switching times ensured by design.

TC1410/TC1410N

DC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise noted, over the operating temperature range with $4.5V \leq V_{DD} \leq 16V$. Typical values are measured at $T_A = +25^\circ C$, $V_{DD} = 16V$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Power Supply						
Power Supply Current	I_S	—	0.5	1.0	mA	$V_{IN} = 3V$, $V_{DD} = 16V$
		—	0.1	0.15		$V_{IN} = 0V$

Note 1: Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5V \leq V_{DD} \leq 16V$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Specified Temperature Range (C)	T_A	0	—	+70	$^\circ C$	
Specified Temperature Range (E)	T_A	-40	—	+85	$^\circ C$	
Maximum Junction Temperature	T_J	—	—	+150	$^\circ C$	
Storage Temperature Range	T_A	-65	—	+150	$^\circ C$	
Package Thermal Resistances						
Thermal Resistance, 8L-MSOP	θ_{JA}	—	211	—	$^\circ C/W$	
Thermal Resistance, 8L-PDIP	θ_{JA}	—	89.3	—	$^\circ C/W$	
Thermal Resistance, 8L-SOIC	θ_{JA}	—	149.5	—	$^\circ C/W$	

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, over operating temperature range with $4.5V \leq V_{DD} \leq 16V$.

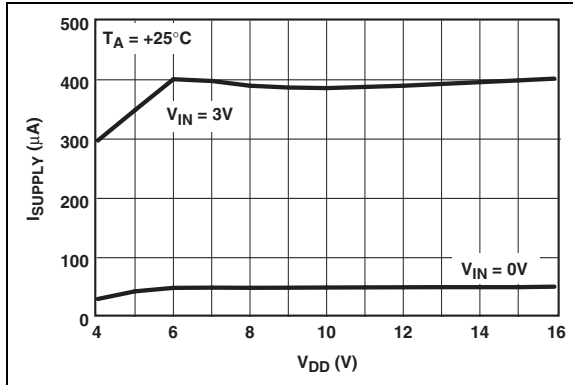


FIGURE 2-1: Quiescent Supply Current vs. Supply Voltage.

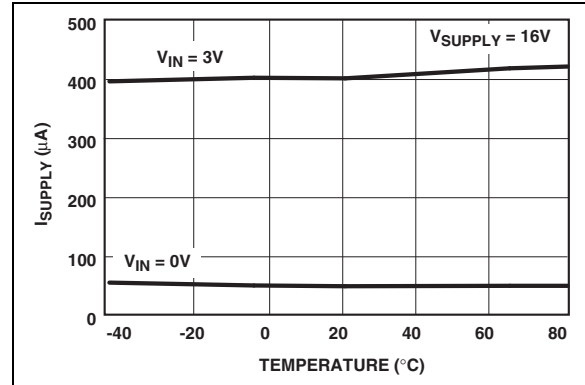


FIGURE 2-4: Quiescent Supply Current vs. Temperature.

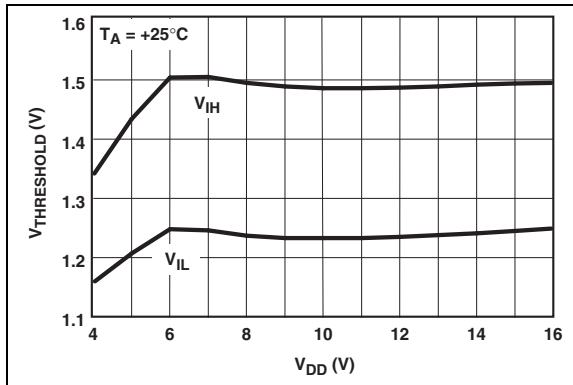


FIGURE 2-2: Input Threshold vs. Supply Voltage.

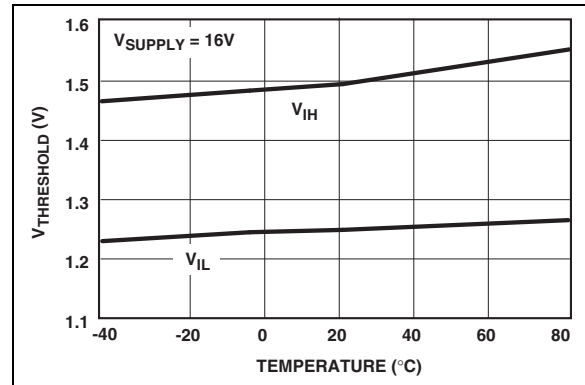


FIGURE 2-5: Input Threshold vs. Temperature.

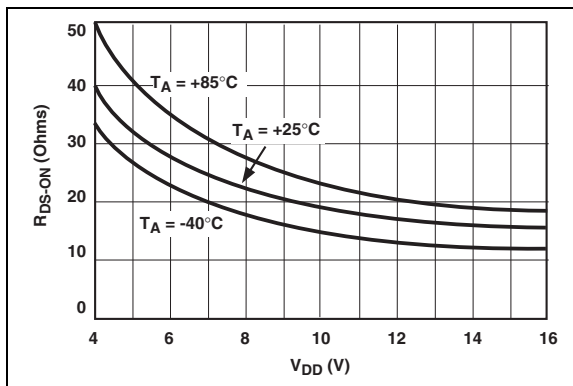


FIGURE 2-3: High-State Output Resistance vs. Supply Voltage.

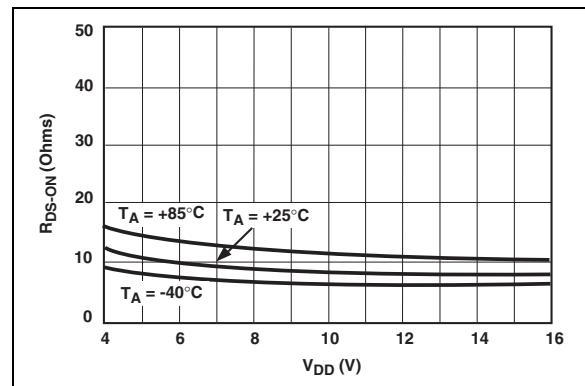


FIGURE 2-6: Low-State Output Resistance vs. Supply Voltage.

TC1410/TC1410N

Note: Unless otherwise indicated, over operating temperature range with $4.5\text{V} \leq V_{DD} \leq 16\text{V}$.

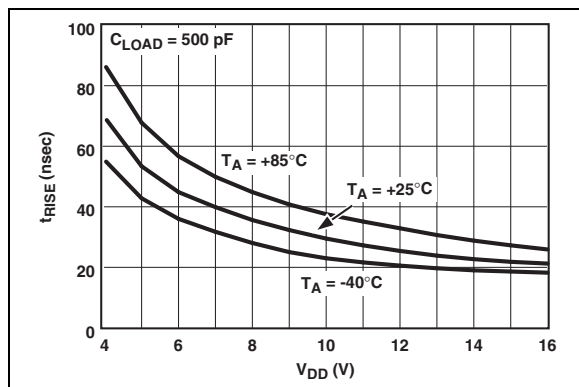


FIGURE 2-7: Rise Time vs. Supply Voltage.

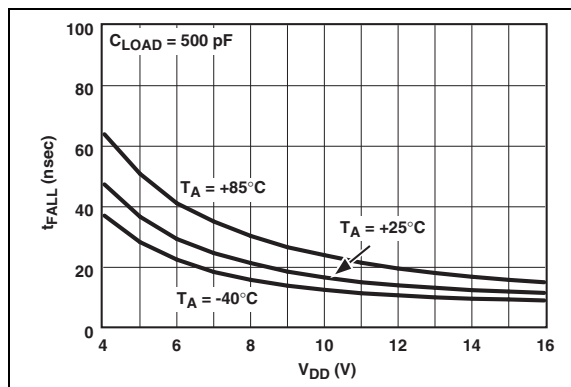


FIGURE 2-10: Fall Time vs. Supply Voltage.

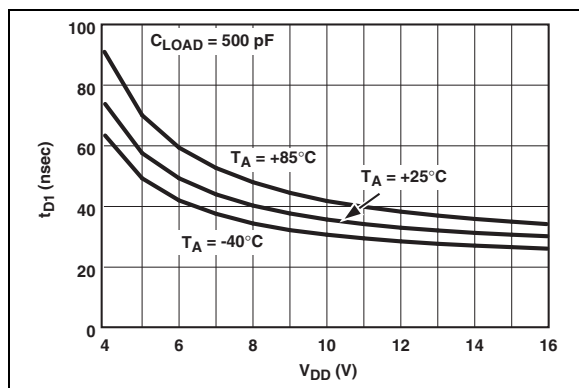


FIGURE 2-8: Propagation Delay vs. Supply Voltage.

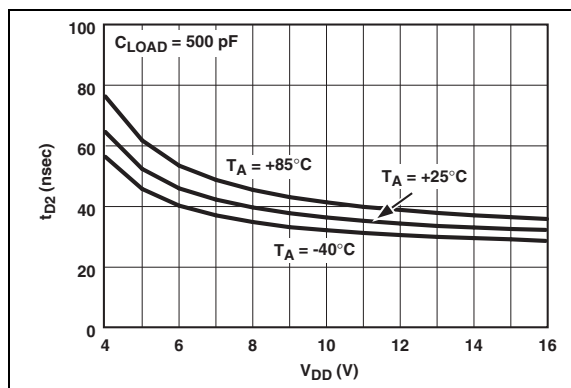


FIGURE 2-11: Propagation Delay vs. Supply Voltage.

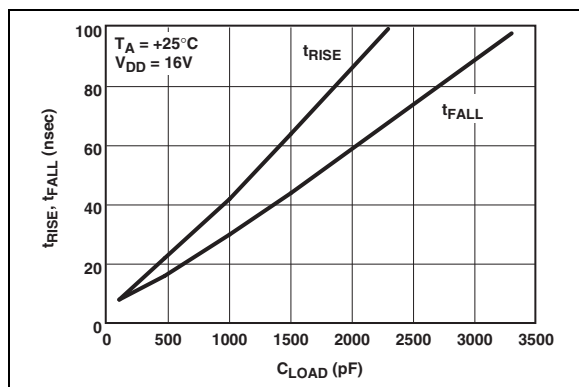


FIGURE 2-9: Rise and Fall Times vs. Capacitive Load.

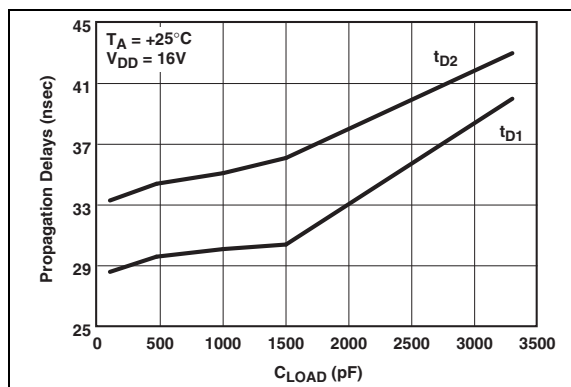


FIGURE 2-12: Propagation Delays vs. Capacitive Load.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in [Table 3-1](#).

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	TC1410 MSOP, PDIP, SOIC	TC1410N MSOP, PDIP, SOIC	Description
1	V _{DD}	V _{DD}	Supply input, 4.5V to 16V
2	IN	IN	Control input
3	NC	NC	No connection
4	GND	GND	Ground
5	GND	GND	Ground
6	$\overline{\text{OUT}}$	OUT	CMOS push-pull output, common to pin 7
7	$\overline{\text{OUT}}$	OUT	CMOS push-pull output, common to pin 6
8	V _{DD}	V _{DD}	Supply input, 4.5V to 16V

3.1 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 16V with respect to the ground pin. The V_{DD} input should be bypassed to ground with a local ceramic capacitor. The value of the capacitor should be chosen based on the capacitive load that is being driven. A value of 1.0 μF is suggested.

3.2 Control Input (IN)

The MOSFET driver input is a high-impedance, TTL/CMOS-compatible input. The input also has 300 mV of hysteresis between the high and low thresholds that prevents output glitching even when the rise and fall time of the input signal is very slow.

3.3 CMOS Push-Pull Output (OUT, $\overline{\text{OUT}}$)

The MOSFET driver output is a low-impedance, CMOS, push-pull style output, capable of driving a capacitive load with 0.5 A peak currents.

3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high peak currents that discharge the load capacitor. The ground pins should be tied into a ground plane or have very short traces to the bias supply source return.

TC1410/TC1410N

4.0 APPLICATIONS INFORMATION

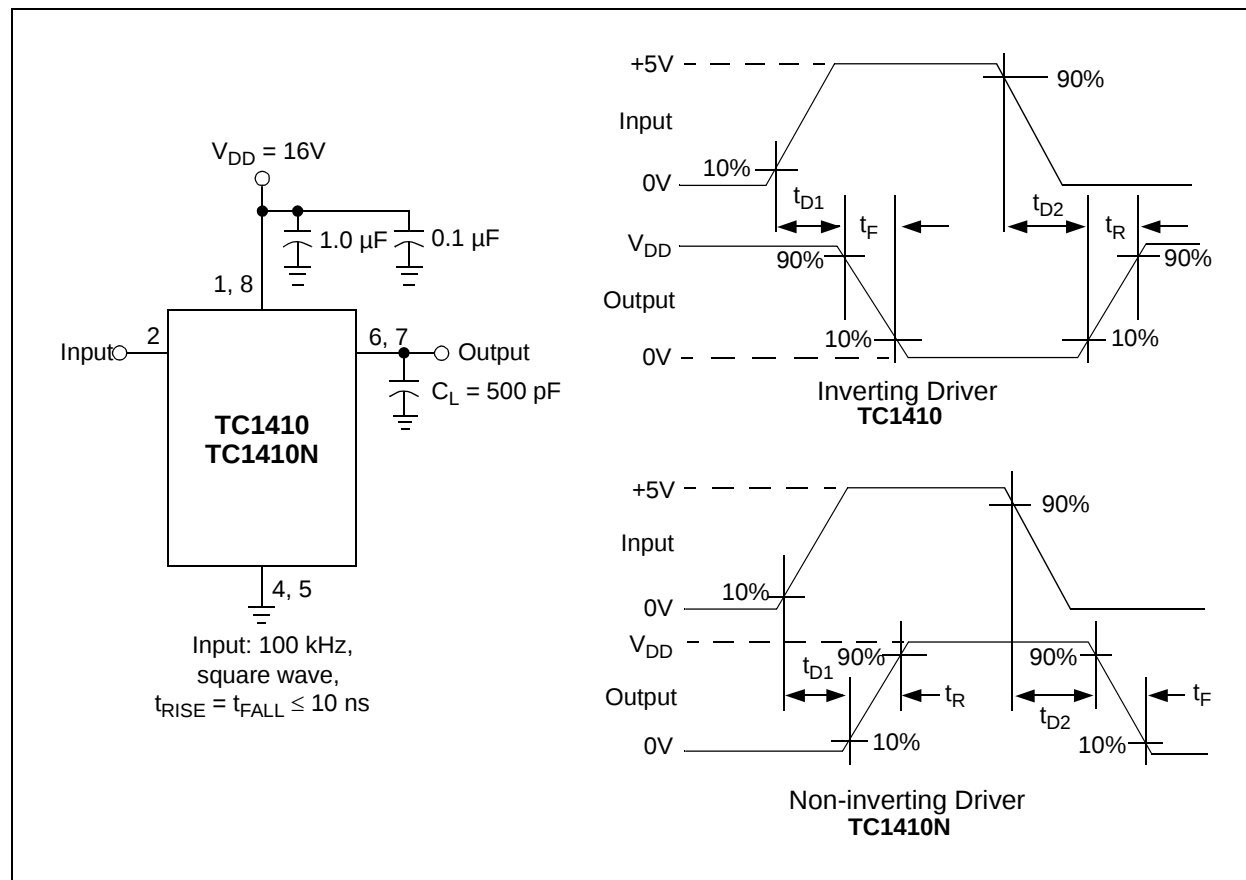
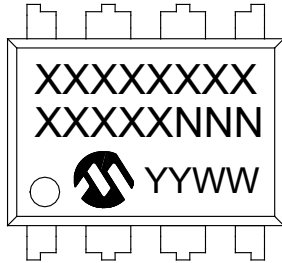


FIGURE 4-1: Switching Time Test Circuit.

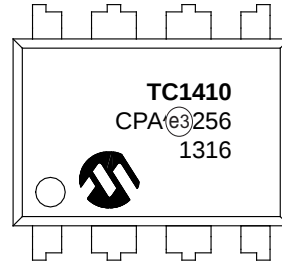
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

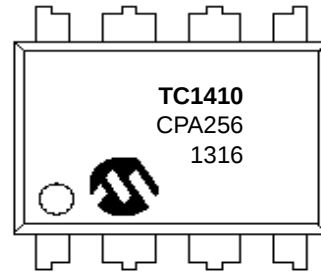
8-Lead PDIP (300 mil)



Example



OR

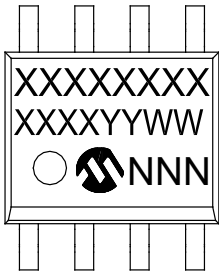


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC [®] designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

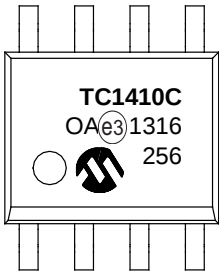
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

TC1410/TC1410N

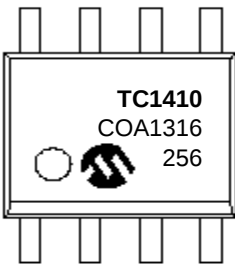
8-Lead SOIC (3.90 mm)



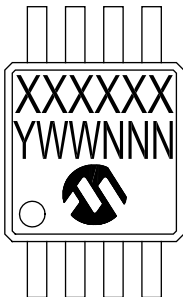
Example



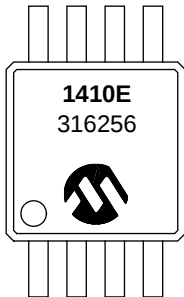
OR



8-Lead MSOP (3x3 mm)

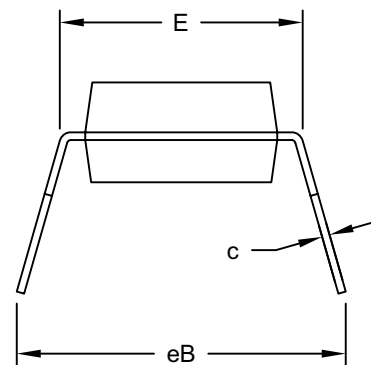
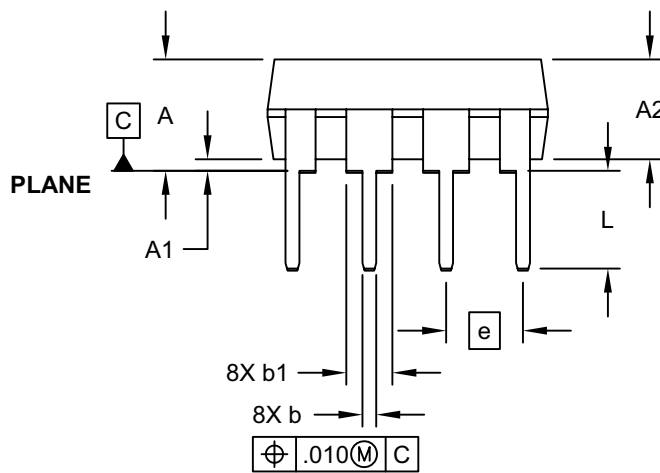
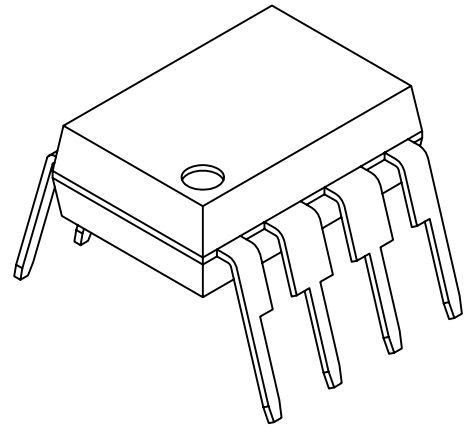
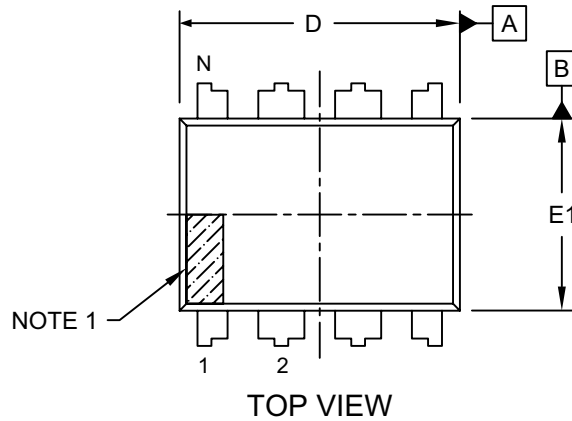


Example



8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

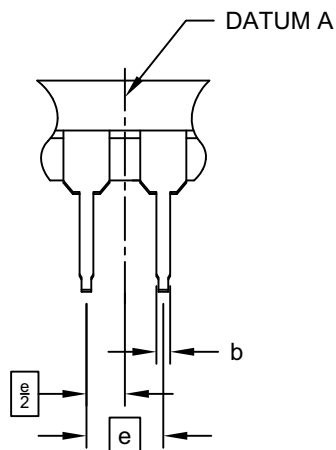
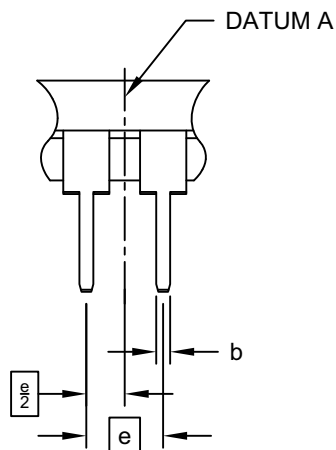


TC1410/TC1410N

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

ALTERNATE LEAD DESIGN (VENDOR DEPENDENT)



Dimension Limits	Units	INCHES		
		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	.100 BSC		
Top to Seating Plane	A	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	-	-	.430

Notes:

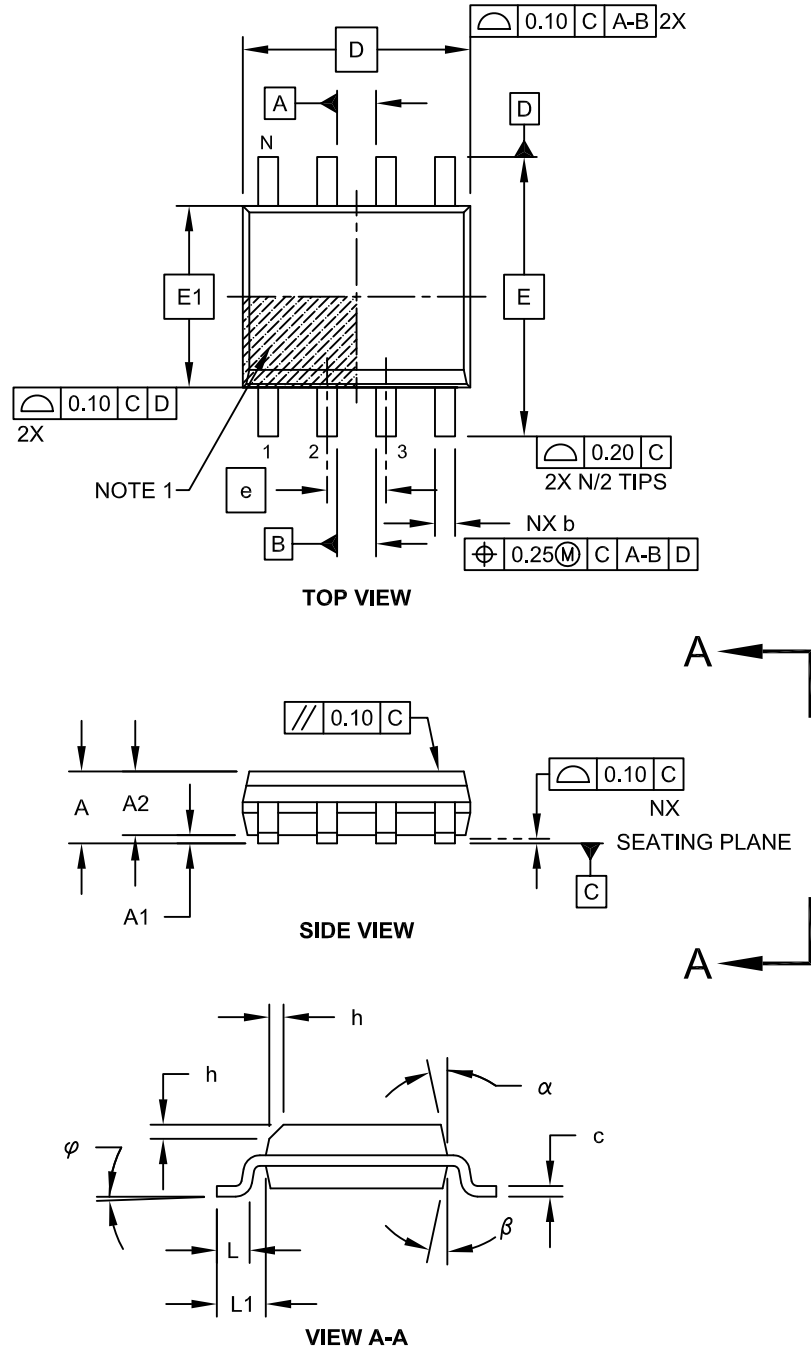
- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-018D Sheet 2 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

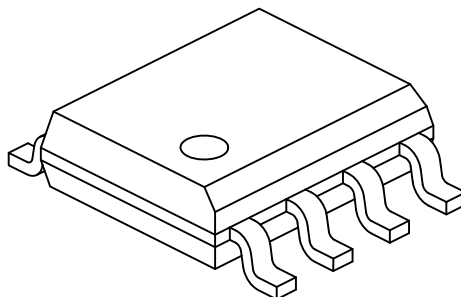


Microchip Technology Drawing No. C04-057C Sheet 1 of 2

TC1410/TC1410N

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



		Units	MILLIMETERS		
Dimension		Limits	MIN	NOM	MAX
Number of Pins	N		8		
Pitch	e		1.27 BSC		
Overall Height	A		-	-	1.75
Molded Package Thickness	A2		1.25	-	-
Standoff §	A1		0.10	-	0.25
Overall Width	E		6.00 BSC		
Molded Package Width	E1		3.90 BSC		
Overall Length	D		4.90 BSC		
Chamfer (Optional)	h		0.25	-	0.50
Foot Length	L		0.40	-	1.27
Footprint	L1		1.04 REF		
Foot Angle	φ		0°	-	8°
Lead Thickness	c		0.17	-	0.25
Lead Width	b		0.31	-	0.51
Mold Draft Angle Top	α		5°	-	15°
Mold Draft Angle Bottom	β		5°	-	15°

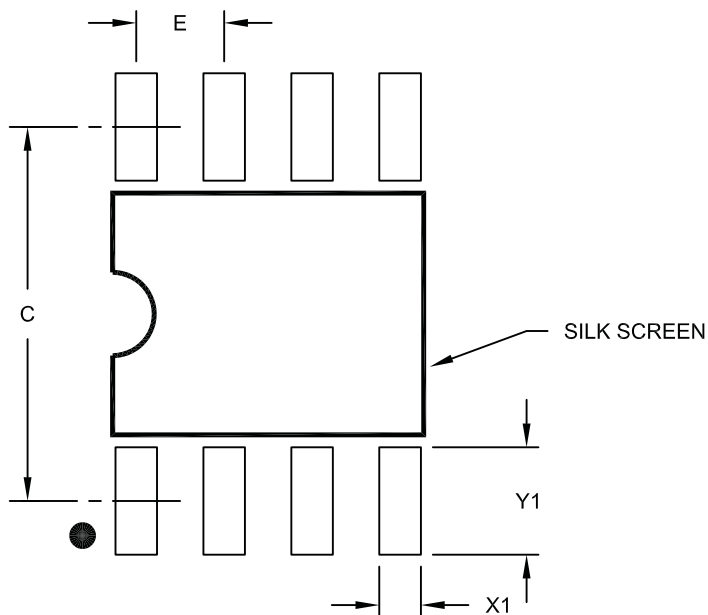
Notes:

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (OA) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

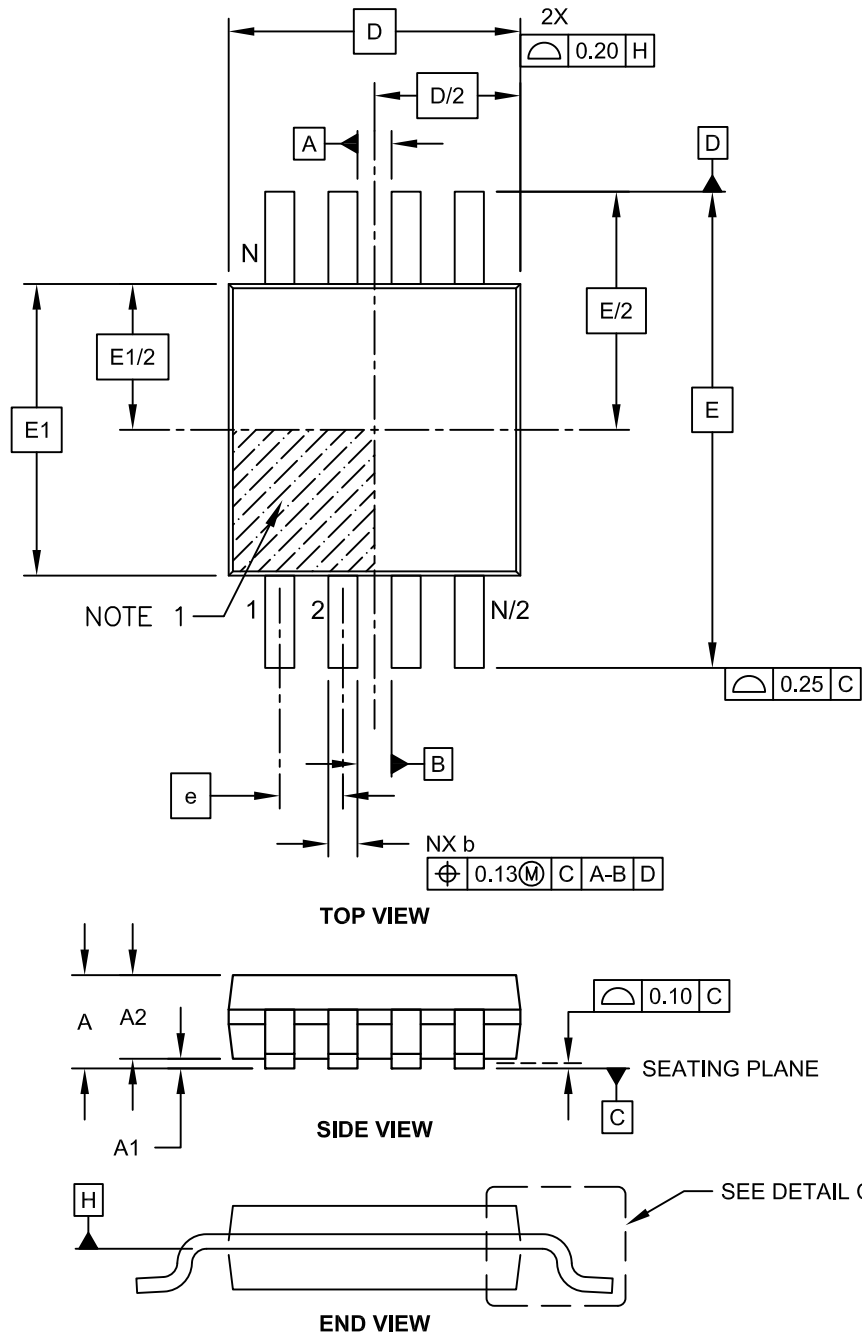
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

TC1410/TC1410N

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

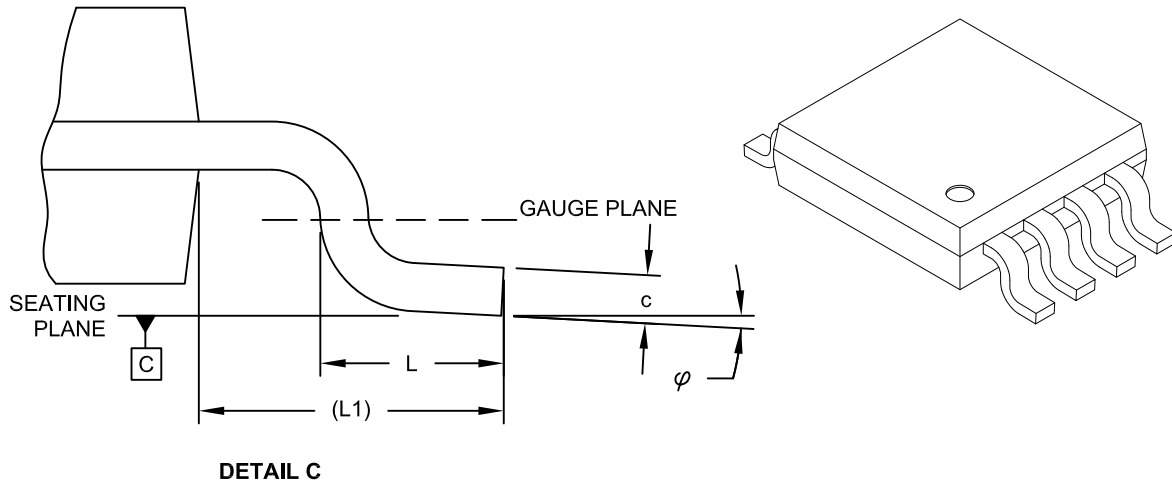
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e	0.65 BSC		
Overall Height	A	-	-	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	-	0.15
Overall Width	E	4.90 BSC		
Molded Package Width	E1	3.00 BSC		
Overall Length	D	3.00 BSC		
Foot Length	L	0.40	0.60	0.80
Footprint	L1	0.95 REF		
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.08	-	0.23
Lead Width	b	0.22	-	0.40

Notes:

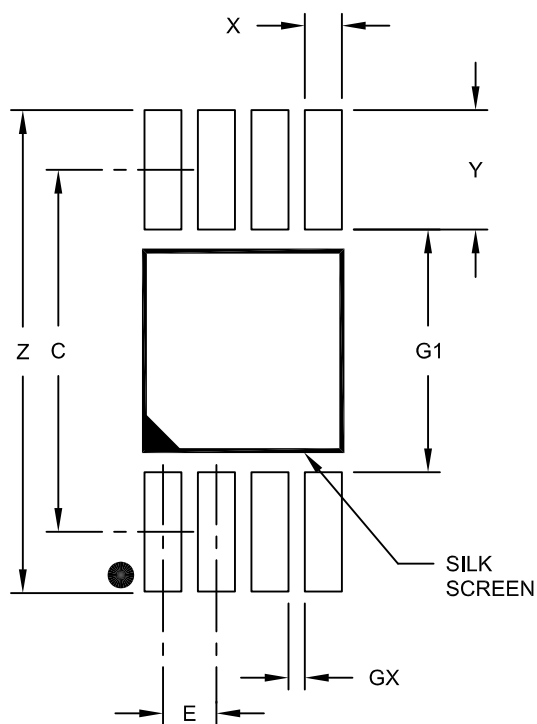
- Pin 1 visual index feature may vary, but must be located within the hatched area.
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

TC1410/TC1410N

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension	Units	MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C		4.40	
Overall Width	Z			5.85
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G1	2.95		
Distance Between Pads	GX	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

NOTES:

APPENDIX A: REVISION HISTORY

Revision F (February 2015)

The following is the list of modifications:

1. Updated package drawings in [Section 5.0 “Packaging Information”](#).
2. Minor typographical changes.

Revision E (May 2013)

The following is the list of modifications:

1. Updated the values for Electrostatic Discharge in the [Features](#) and [General Description](#) columns.
2. Updated the Pin Description table in [Section 3.0 “Pin Descriptions”](#).

NOTES:

TC1410/TC1410N

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>X</u>	<u>/XX</u>
Device	Temperature Range	Package
Device: TC1410: 0.5A Single MOSFET Driver, Inverting TC1410N: 0.5A Single MOSFET Driver, Non-inverting Temperature Range: C = 0°C to +70°C E = -40°C to +85°C Package: OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel) UA = Plastic Micro Small Outline (MSOP), 8-lead * UA713 = Plastic Micro Small Outline (MSOP), 8-lead * (Tape and Reel) PA = Plastic DIP (300 mil Body), 8-lead * MSOP package is only available in E-Temp.		
Examples: a) TC1410COA: 0.5A Single MOSFET driver, SOIC package, 0°C to +70°C. b) TC1410CPA: 0.5A Single MOSFET driver, PDIP package, 0°C to +70°C. c) TC1410EUA713: Tape and Reel, 0.5A Single MOSFET driver, MSOP package, -40°C to +85°C. a) TC1410NCPA: 0.5A Single MOSFET driver, PDIP package, 0°C to +70°C. b) TC1410NEPA: 0.5A Single MOSFET driver, PDIP package, -40°C to +85°C. c) TC1410NEUA: 0.5A Single MOSFET driver, MSOP package, -40°C to +85°C.		

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